

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

# TLP3021(S), TLP3022(S), TLP3023(S)

OFFICE MACHINE  
 HOUSEHOLD USE EQUIPMENT  
 TRIAC DRIVER  
 SOLID STATE RELAY

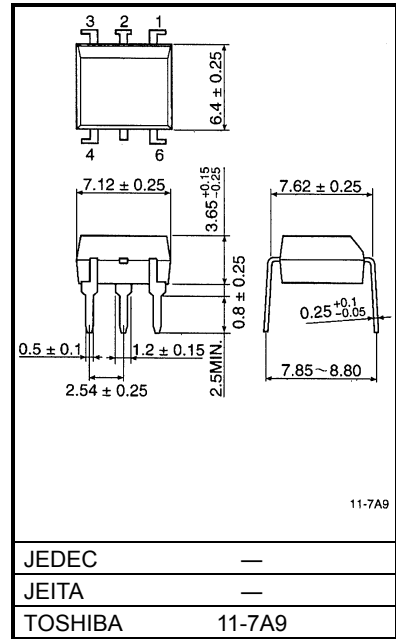
The TOSHIBA TLP3021 (S), TLP3022 (S) and TLP3023 (S) consist of photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP.

- Peak Off-State Voltage : 400 V (min)
- Trigger LED Current : 15 mA (max) (TLP3021(S))  
 10 mA (max) (TLP3022(S))  
 5 mA (max) (TLP3023(S))
- On-State Current : 100 mA (max)
- Isolation Voltage : 5000Vrms(Min)
- UL Recognized : UL1577, File No. E67349
- SEMKO Approved : SS EN60065  
 SS EN60950, File No. 9841105
- BSI Approved : BS EN60065, File No. 8385  
 BS EN60950, File No. 8386
- Option (D4) type  
 VDE approved: DIN EN60747-5-2  
 Approved No. 40009302  
 Maximum operating insulation voltage: 890V<sub>PK</sub>  
 Highest permissible over voltage: 8000V<sub>PK</sub>  
 (Note): When a EN60747-5-2 approved type is needed,  
 please designate the "Option (D4)"

● Construction Mechanical Rating

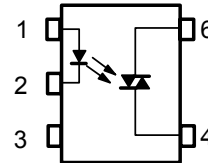
	7.62 mm pich Standard Type	10.16 mm pich TLPxxxxF Type
Creepage Distance	7.0 mm (Min)	8.0 mm (Min)
Clearance	7.0 mm (Min)	8.0 mm (Min)
Insulation Thickness	0.5 mm (Min)	0.5 mm (Min)

Unit: mm



Weight: 0.39g (typ.)

**Pin Configuration  
(top view)**



- 1: Anode
- 2: Cathode
- 3: N.C.
- 4: Terminal 1
- 6: Terminal 2

## Absolute Maximum Ratings (Ta=25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
LED	Forward Current	$I_F$	50	mA	
	Forward Current Derating (Ta≥53°C)	$\Delta I_F / ^\circ\text{C}$	-0.7	mA / °C	
	Peak Forward Current (100µs pulse, 100pps)	$I_{FP}$	1	A	
	Power Dissipation	$P_D$	100	mW	
	Power Dissipation Derating (Ta≥25°C)	$\Delta P_D / ^\circ\text{C}$	-1.0	mW / °C	
	Reverse Voltage	$V_R$	5	V	
	Junction Temperature	$T_j$	125	°C	
DETECTOR	Off-State Output Terminal Voltage	$V_{DRM}$	400	V	
	On-State RMS Current	Ta=25°C	$I_{T(RMS)}$	100	mA
		Ta=70°C		50	
	On-State Current Derating (Ta≥25°C)	$\Delta I_T / ^\circ\text{C}$	-1.1	mA / °C	
	Peak On-State Current (100µs pulse, 120pps)	$I_{TP}$	2	A	
	Peak Nonrepetitive Surge Current (Pw=10ms)	$I_{TSM}$	1.2	A	
	Power Dissipation	$P_D$	300	mW	
	Power Dissipation Derating (Ta≥25°C)	$\Delta P_D / ^\circ\text{C}$	-4.0	mW / °C	
	Junction Temperature	$T_j$	115	°C	
Storage Temperature Range	$T_{stg}$	-55 to 150	°C		
Operating Temperature Range	$T_{opr}$	-40 to 100	°C		
Lead Soldering Temperature (10s)	$T_{sol}$	260	°C		
Total Package Power Dissipation	$P_T$	330	mW		
Total Package Power Dissipation Derating (Ta≥25°C)	$\Delta P_T / ^\circ\text{C}$	-4.4	mW / °C		
Isolation Voltage (AC, 1min., R.H.≤60%)	(Note 2) $BV_S$	5000	$V_{rms}$		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 2) Device considered a two terminal device :Pins1,2 and 3 shorted together and pin4 and pin6 shorted together.

## Recommended Operating Conditions

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	$V_{AC}$	—	—	120	$V_{ac}$
Forward Current	$I_F^*$	15	20	25	mA
Peak On-State Current	$I_{TP}$	—	—	1	A
Operating Temperature	$T_{opr}$	-25	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

\*In The case of TLP3022

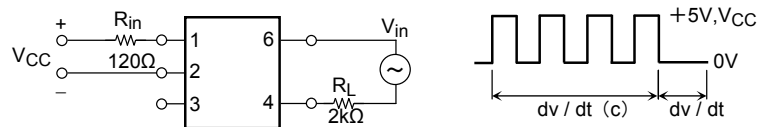
## Individual Electrical Characteristics (Ta=25°C)

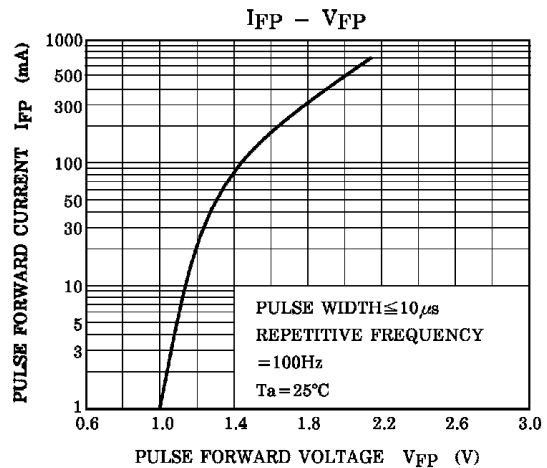
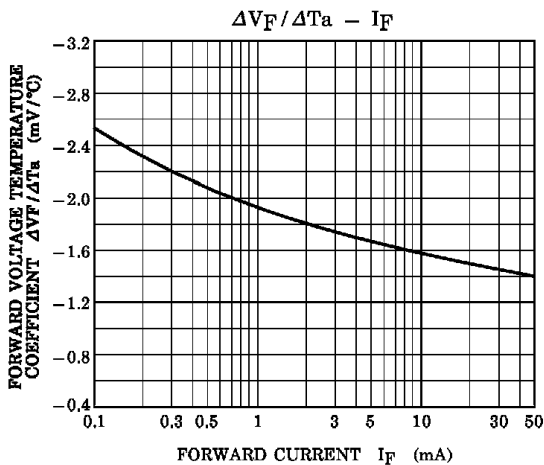
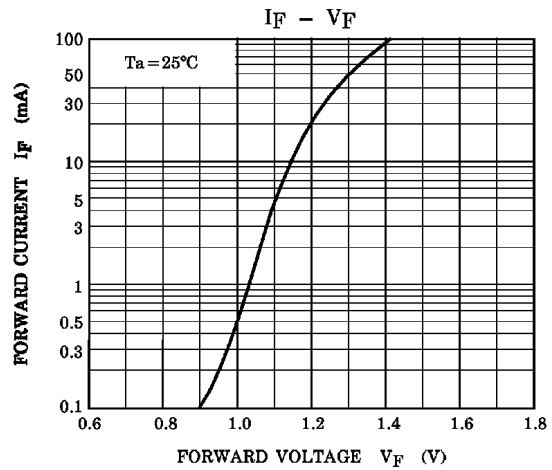
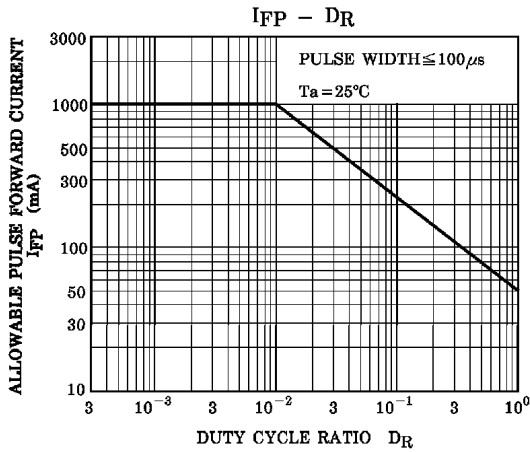
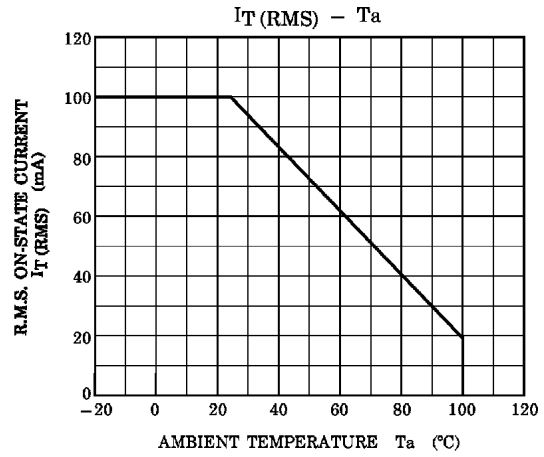
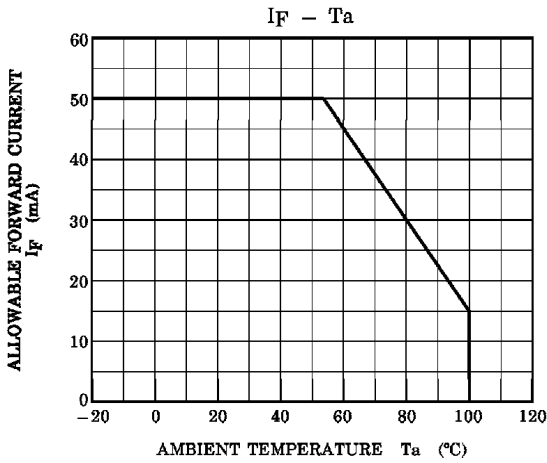
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	$V_F$	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse Current	$I_R$	$V_R = 5 \text{ V}$	—	—	10	$\mu\text{A}$
	Capacitance	$C_T$	$V = 0, f = 1\text{MHz}$	—	10	—	pF
DIODE	Peak Off-State Current	$I_{DRM}$	$V_{DRM} = 400\text{V}$	—	10	1000	nA
	Peak On-State Voltage	$V_{TM}$	$I_{TM} = 100\text{mA}$	—	1.7	3.0	V
	Holding Current	$I_H$	—	—	0.6	—	mA
	Critical Rate of Rise of Off-State Voltage	$dv/dt$	$V_{in} = 120\text{Vrms}, T_a = 85^\circ\text{C}$ (Fig.1)	200	500	—	$\text{V}/\mu\text{s}$
	Critical Rate of Rise of Commutating Voltage	$dv/dt(c)$	$V_{in} = 30\text{Vrms}, I_T = 15\text{mA}$ (Fig.1)	—	0.2	—	$\text{V}/\mu\text{s}$

## Coupled Electrical Characteristics (Ta=25°C)

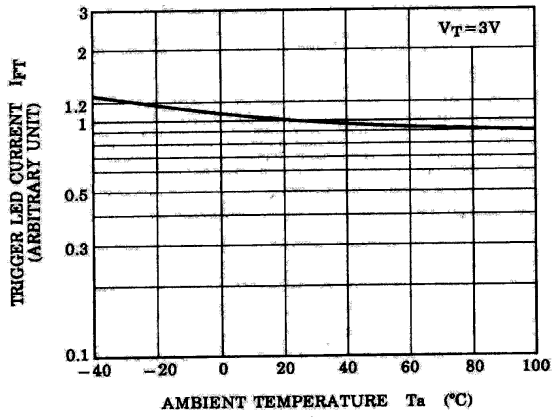
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	TLP3021(S)	$I_{FT}$	$V_T = 3\text{V}$	—	—	15	mA
	TLP3022(S)			—	5	10	
	TLP3023(S)			—	—	5	
Capacitance (Input to Output)		$C_S$	$V_S = 0, f = 1\text{MHz}$	—	0.8	—	pF
Isolation Resistance		$R_S$	$V_S = 500\text{V} (\text{R.H.} \leq 60\%)$	$5 \times 10^{10}$	$10^{14}$	—	$\Omega$
Isolation Voltage		$BV_S$	AC, 1minute	5000	—	—	Vrms
			AC, 1second, in oil	—	10000	—	
			DC, 1minute, in oil	—	10000	—	Vdc

Fig. 1  $dv/dt$  test circuit

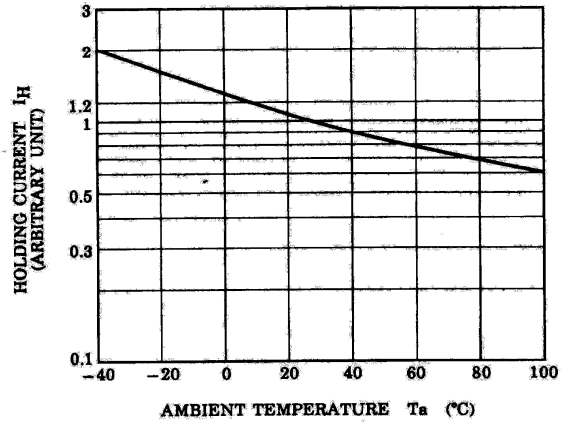




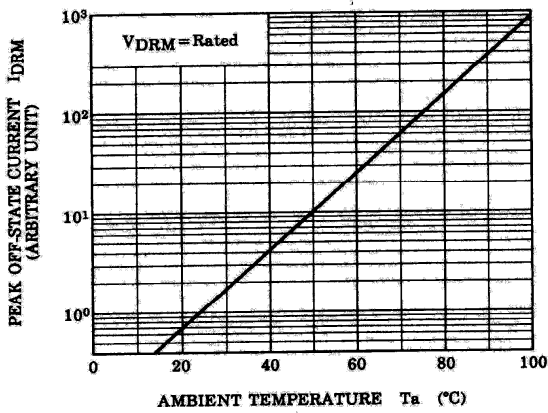
NORMALIZED  $I_{FT} - T_a$



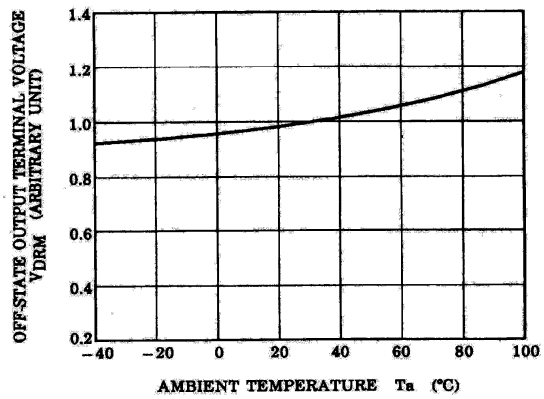
NORMALIZED  $I_H - T_a$



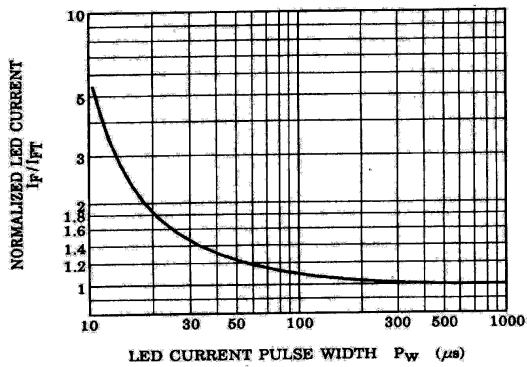
NORMALIZED  $I_{DRM} - T_a$



NORMALIZED  $V_{DRM} - T_a$



NORMALIZED LED CURRENT  
- LED CURRENT PULSE WIDTH



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